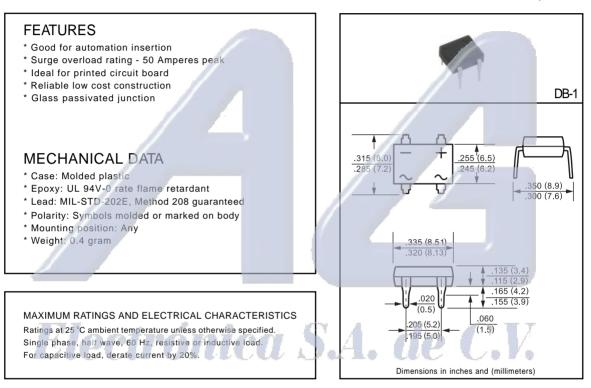
DB101 THRU DB107

TECHNICAL SPECIFICATIONS OF SINGLE-PHASE SILICON BRIDGE RECTIFIER

VOLTAGE RANGE - 50 to 1000 Volts

CURRENT - 1.0 Ampere



		SYMBOL	DB101	DB102	DB103	DB104	DB105	DB106	DB107	UNITS
Maximum Recurrent Peak Reverse Voltage		Vrrm	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage		Vrms	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Output Current at TA = 40°C		lo	1.0							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)		IFSM	50						Amps	
Maximum Forward Voltage Drop per element at 1.0A DC		Vf	1.1							Volts
Maximum DC Reverse Current at Rated	@TA = 25°C	IR	10							uAmps
DC Blocking Voltage per element	@TA = 125°C		500							
I ² t Rating for Fusing (t<8.3ms)		l ² t	10							A ² Sec
Typical Junction Capacitance (Note1)		CJ	25							pF
Typical Thermal Resistance (Note 2)		RθJA	40							°C/W
Operating and Storage Temperature Range		T J,TSTG	-65 to + 150							°C

NOTES : 1. Measured at 1 MHz and applied reverse voltage of 4.0 volts

2. Thermal Resistance from Junction to Ambient and from junction to lead mounted on P.C.B. with 0.5 x 0.5" (13x13mm) copper pads.

RATING AND CHARACTERISTIC CURVES (DB101 THRU DB107)

